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Joseph F. Hetz - Reg. No. 41,070

Name of Applicant, Assignee or
Registered Representative

Signature

Our Case No. 10519-57

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

| | | | |
|-----------------------|---|---|----------------------|
| In re Application of: |) | | |
| Herner et al. |) | | |
| Serial No.: | 09/928,975 |) | Examiner: T. Magee |
| Filed: | August 13, 2001 |) | Group Art Unit: 2811 |
| For: | Low Resistivity Titanium Silicide on Heavily Doped Semiconductor |) | |

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AMENDMENT AND RECORD OF INTERVIEW

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Dear Sir:

Please enter the following amendment and remarks in response to the Office Action mailed January 6, 2003.

IN THE CLAIMS

Please amend Claim 8 as follows. Appendix A (at Tab A) contains a marked-up version of this claim showing the changes being made.